MUR3020PT, MUR3040PT, MUR3060PT

SWITCHMODE™ Power Rectifiers

These state−of−the−art devices are designed for use in switching power supplies, inverters and as free wheeling diodes.

Features

- Ultrafast 35 and 60 Nanosecond Recovery Time
- 175°C Operating Junction Temperature
- High Voltage Capability to 600 V
- Low Forward Drop
- Low Leakage Specified @ 150°C Case Temperature
- Current Derating Specified @ Both Case and Ambient Temperatures
- Epoxy Meets UL 94 V−0 @ 0.125 in
- High Temperature Glass Passivated Junction
- Pb−Free Packages are Available*

Mechanical Characteristics:

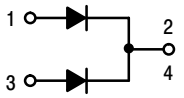
- Case: Epoxy, Molded
- Weight: 4.3 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max for 10 Seconds
- Shipped 30 Units Per Plastic Tube

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

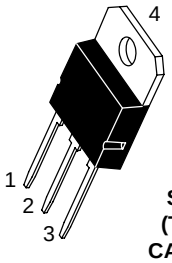
ON Semiconductor®

http://onsemi.com

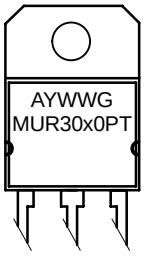
ULTRAFAST RECTIFIERS 30 AMPERES, 200−600 VOLTS



MARKING DIAGRAM



SOT−93 (TO−218) CASE 340D STYLE 2



A = Assembly Location
Y = Year
WW = Work Week
G = Pb−Free Package
MUR30x0PT = Device Code
x = 2, 4, or 6

ORDERING INFORMATION

Device	Package	Shipping
MUR3020PT	SOT−93	30 Units/Rail
MUR3020PTG	SOT−93 (Pb−Free)	30 Units/Rail
MUR3040PT	SOT−93	30 Units/Rail
MUR3040PTG	SOT−93 (Pb−Free)	30 Units/Rail
MUR3060PT	SOT−93	30 Units/Rail
MUR3060PTG	SOT−93 (Pb−Free)	30 Units/Rail

MAXIMUM RATINGS (Per Leg)

Rating	Symbol	MUR3020PT	MUR3040PT	MUR3060PT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	200	400	600	V
Average Rectified Forward Current (Rated V_R) Per Leg Per Device	$I_{F(AV)}$	15 @ T_C = 150°C 30 @ T_C = 150°C		15 @ T_C = 30 145°C	A
Peak Rectified Forward Current, Per Leg (Rated V_R, Square Wave, 20 kHz, T_C = 150°C)	I_{FRM}	30 @ T_C = 150°C		30 @ T_C =145°C	A
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions, halfwave, single phase, 60 Hz) Per Leg	I_{FSM}	200			A
Operating Junction and Storage Temperature	T_J, T_{stg}	− 65 to +175			°C

THERMAL CHARACTERISTICS (Per Diode Leg)

Maximum Thermal Resistance, − Junction−to−Case − Junction−to−Ambient	 $R_{\theta JC}$ $R_{\theta JA}$	 1.5 40	°C/W

ELECTRICAL CHARACTERISTICS (Per Diode Leg)

Maximum Instantaneous Forward Voltage (Note 1) (I_F = 15 Amp, T_C = 150°C) (I_F = 15 Amp, T_C = 25°C)	V_F	 0.85 1.05	 1.12 1.25	 1.2 1.5	V
Maximum Instantaneous Reverse Current (Note 1) (Rated DC Voltage, T_J = 150°C) (Rated DC Voltage, T_J = 25°C)	i_R	 500 10		 1000 10	μA
Maximum Reverse Recovery Time (i_F = 1.0 A, di/dt = 50 A/μs)	t_{rr}	35	60		ns

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2.0%.

MUR3020PT

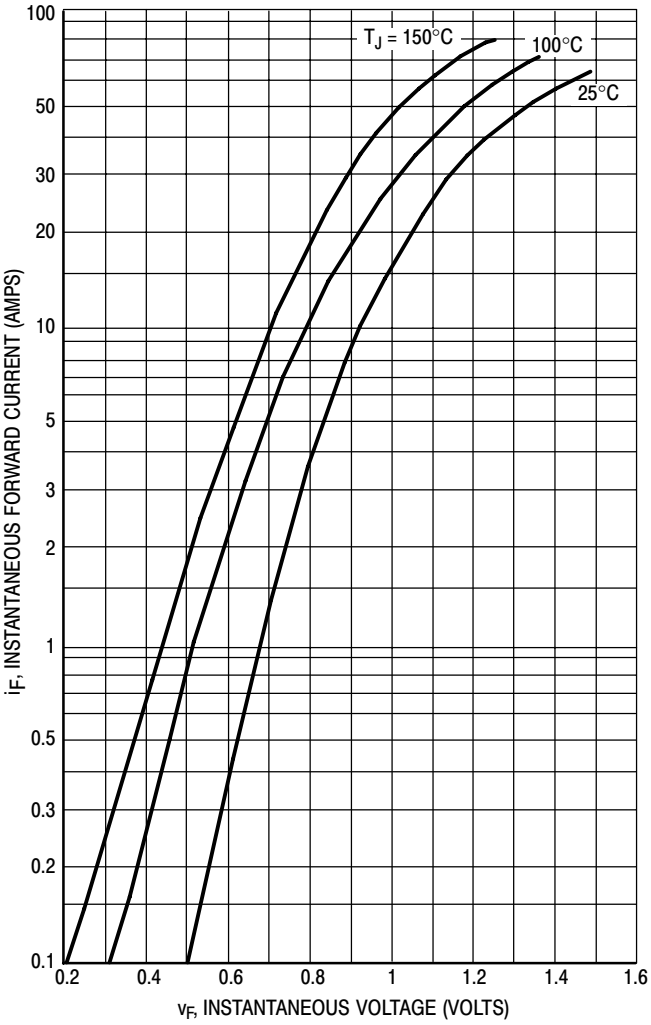


Figure 1. Typical Forward Voltage (Per Leg)

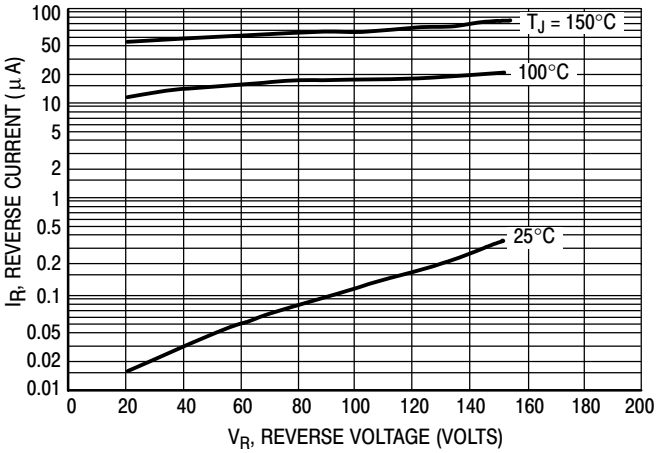


Figure 2. Typical Reverse Current (Per Leg)

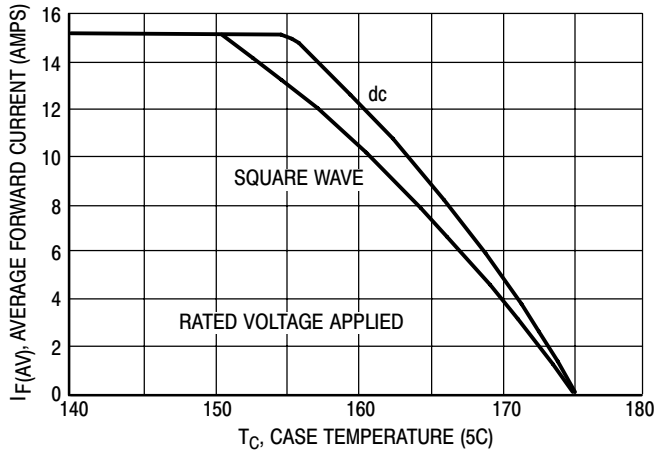


Figure 3. Current Derating, Case (Per Leg)

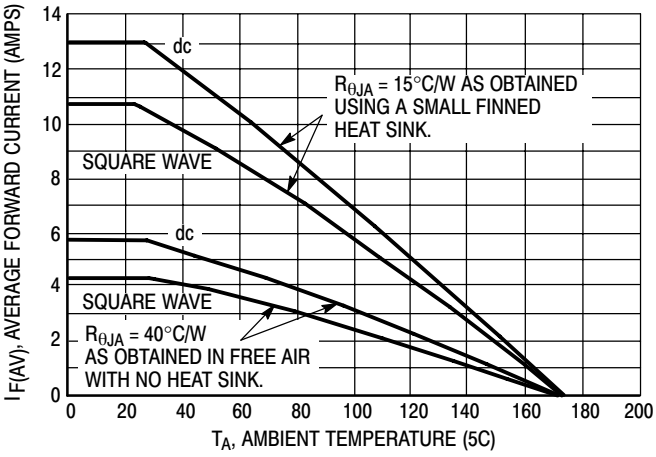


Figure 4. Current Derating, Ambient (Per Leg)

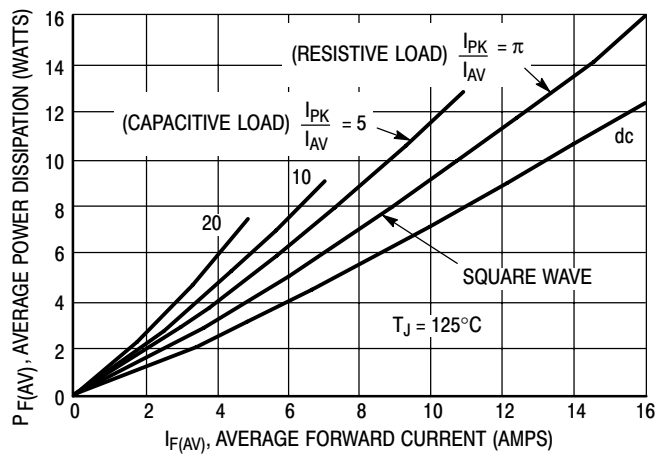


Figure 5. Power Dissipation (Per Leg)

MUR3040PT

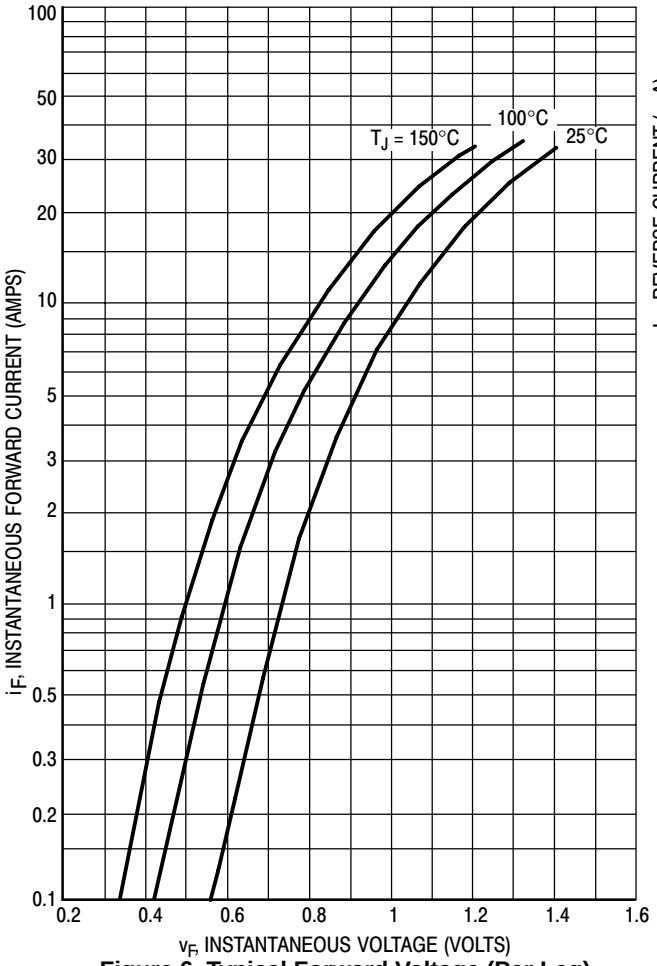


Figure 6. Typical Forward Voltage (Per Leg)

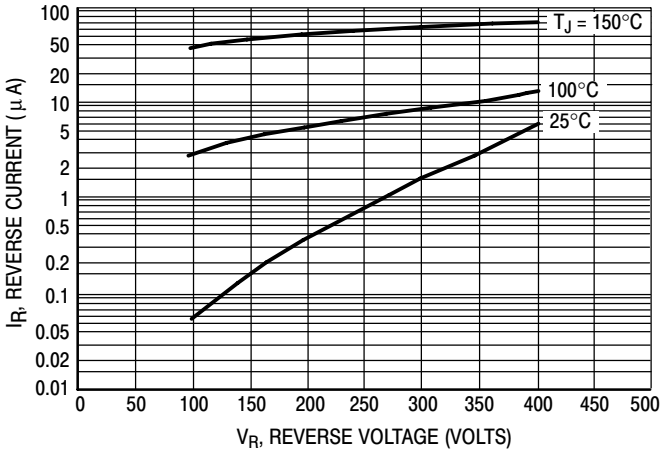


Figure 7. Typical Reverse Current (Per Leg)

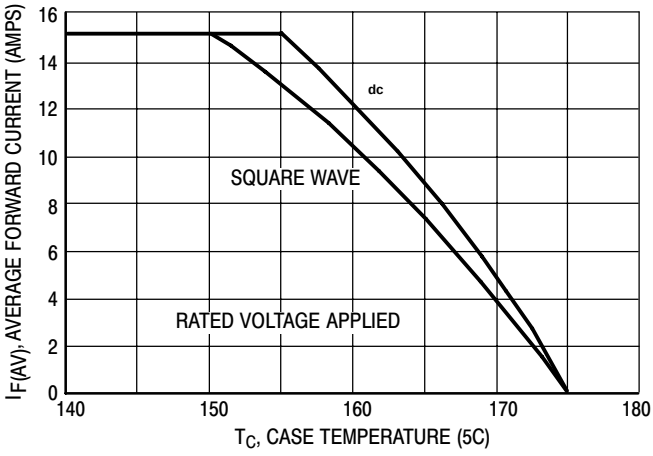


Figure 8. Current Derating, Case (Per Leg)

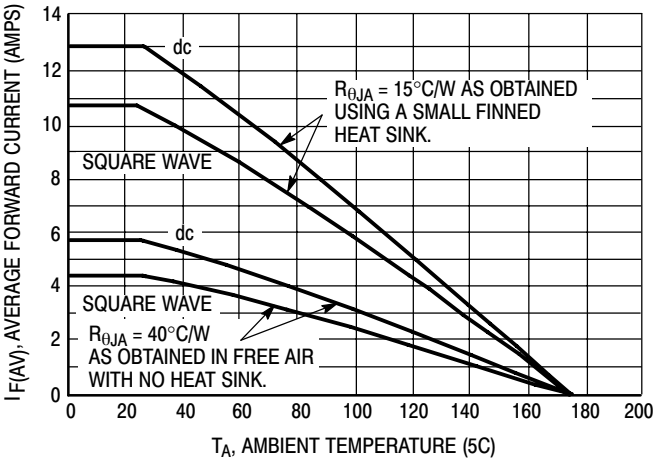


Figure 9. Current Derating, Ambient (Per Leg)

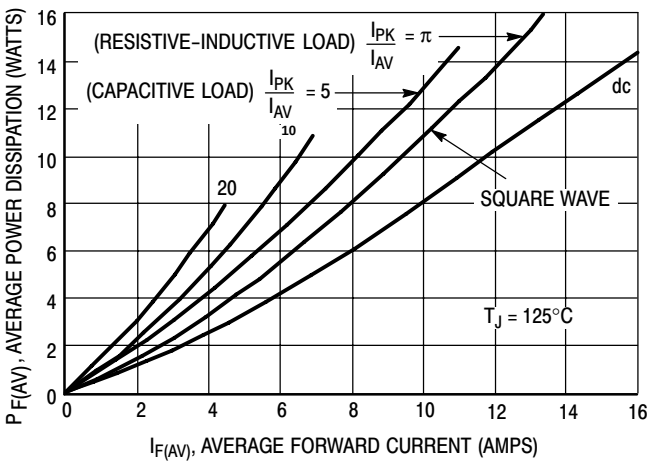


Figure 10. Power Dissipation (Per Leg)

MUR3060PT

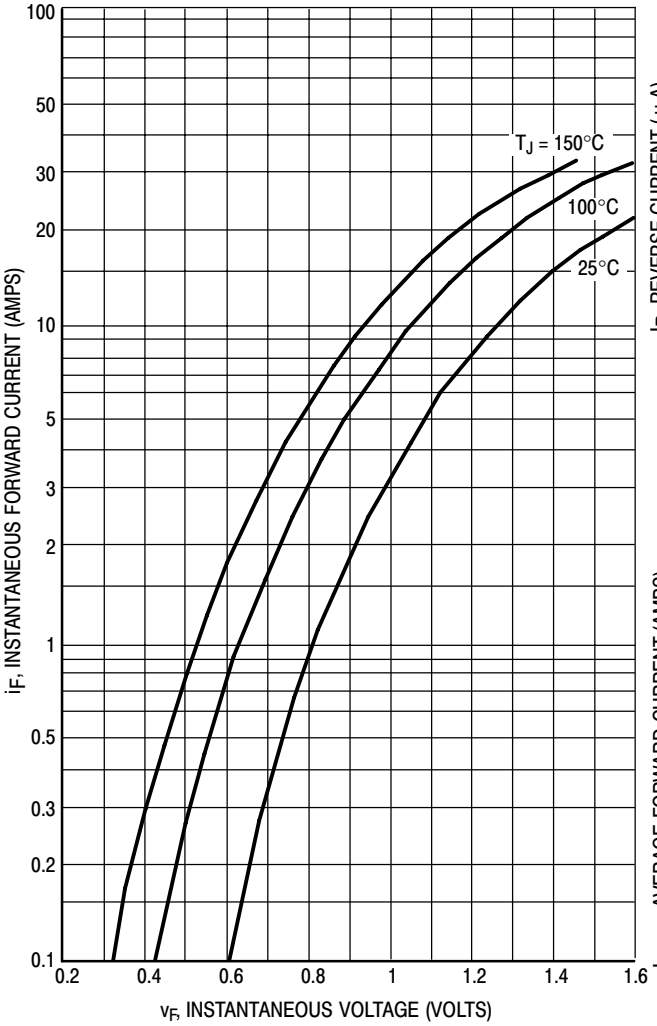


Figure 11. Typical Forward Voltage (Per Leg)

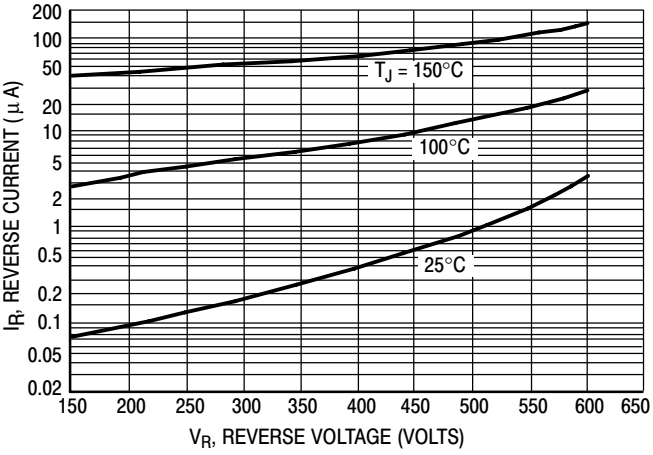


Figure 12. Typical Reverse Current (Per Leg)

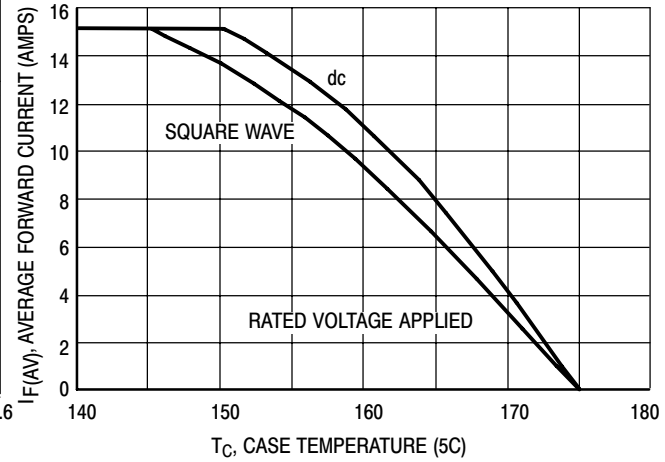


Figure 13. Current Derating, Case (Per Leg)

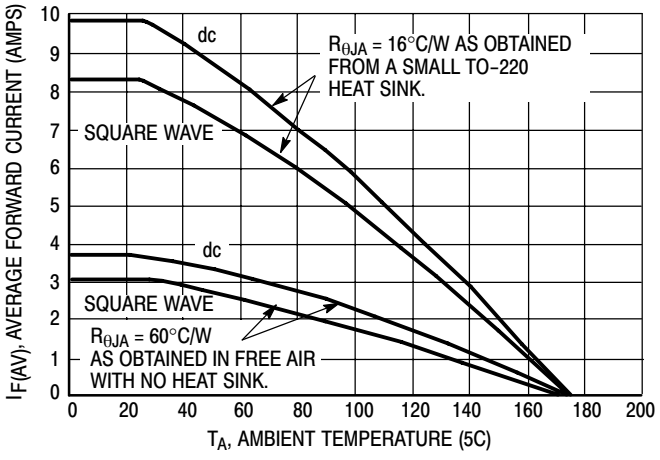


Figure 14. Current Derating, Ambient (Per Leg)

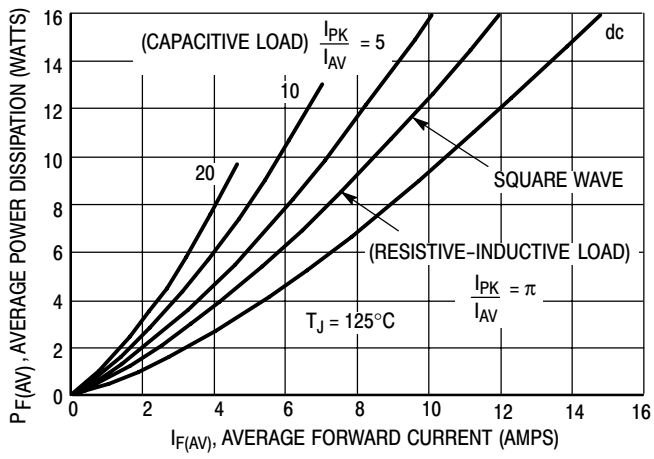


Figure 15. Power Dissipation (Per Leg)

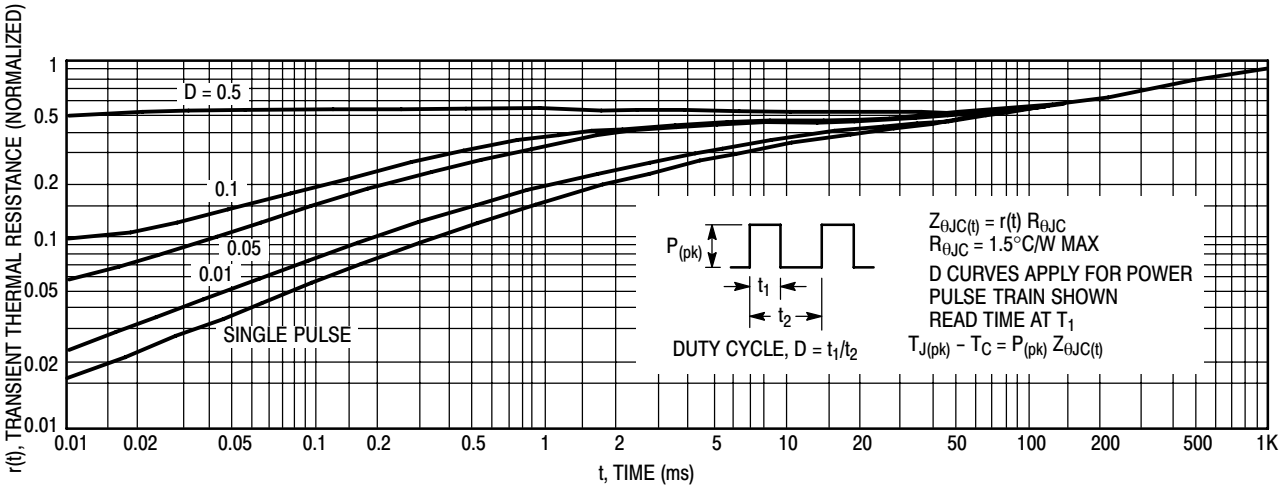


Figure 16. Thermal Response

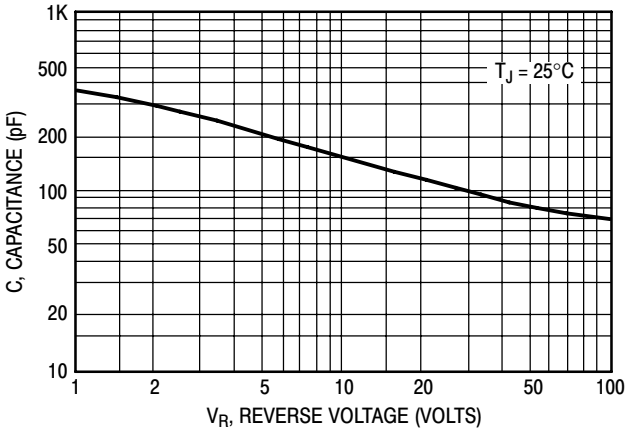
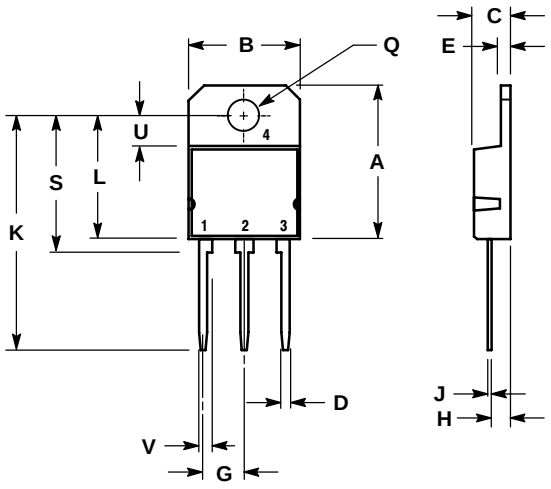


Figure 17. Typical Capacitance (Per Leg)

PACKAGE DIMENSIONS

SOT−93 (TO−218)
CASE 340D−02
ISSUE E



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	---	20.35	---	0.801
B	14.70	15.20	0.579	0.598
C	4.70	4.90	0.185	0.193
D	1.10	1.30	0.043	0.051
E	1.17	1.37	0.046	0.054
G	5.40	5.55	0.213	0.219
H	2.00	3.00	0.079	0.118
J	0.50	0.78	0.020	0.031
K	31.00 REF		1.220 REF	
L	---	16.20	---	0.638
Q	4.00	4.10	0.158	0.161
S	17.80	18.20	0.701	0.717
U	4.00 REF		0.157 REF	
V	1.75 REF		0.069	

STYLE 2:
PIN 1. ANODE 1
2. CATHODE(S)
3. ANODE 2
4. CATHODE(S)

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PUBLICATION ORDERING INFORMATION

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